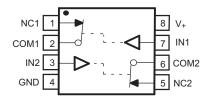
0.9-Ω DUAL SPST ANALOG SWITCH 5-V/3.3-V 2-CHANNEL ANALOG SWITCH

Check for Samples: TS5A23167

FEATURES

- Isolation in Powered-Off Mode, V₊ = 0
- Low ON-State Resistance (0.9 Ω)
- Control Inputs Are 5.5-V Tolerant
- Low Charge Injection
- Low Total Harmonic Distortion (THD)
- 1.65-V to 5.5-V Single-Supply Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78. Class II
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model(A114-B, Class II)
 - 1000-V Charged-Device Model (C101)

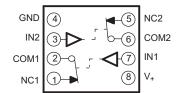
SSOP OR VSSOP PACKAGE (TOP VIEW)



APPLICATIONS

- Cell Phones
- PDAs
- Portable Instrumentation
- Audio and Video Signal Routing
- Low-Voltage Data Acquisition Systems
- Communication Circuits
- Modems
- Hard Drives
- Computer Peripherals
- Wireless Terminals and Peripherals

YZP PACKAGE (BOTTOM VIEW)



DESCRIPTION/ORDERING INFORMATION

The TS5A23167 is a dual single-pole single-throw (SPST) analog switch that is designed to operate from 1.65 V to 5.5 V. The device offers a low ON-state resistance. The device has excellent total harmonic distortion (THD) performance and consumes very low power. These features make this device suitable for portable audio applications.

ORDERING INFORMATION

T _A	PACKAGE ⁽¹⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING (2)
-40°C to 85°C	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Tape and reel	TS5A23167YZPR	J87
	SSOP - DCT	Tape and reel	TS5A23167DCTR	JAP_
	VSSOP - DCU (Pb-free)	Tape and reel	TS5A23167DCUR	JAP_

⁽¹⁾ Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

⁽²⁾ DCT: The actual top-side marking has three additional characters that designate the year, month, and assembly/test site.

DCU: The acutal top-side marking has one additional character that designates the assembly/test site.

YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).



SUMMARY OF CHARACTERISTICS(1)

Configuration	Dual Single Pole Single Throw (2 × SPST)
Number of channels	2
ON-state resistance (r _{on})	0.9 Ω
ON-state resistance match (Δr _{on})	0.1 Ω
ON-state resistance flatness (r _{on(flat)})	0.25 Ω
Turn-on/turn-off time (t _{ON} /t _{OFF})	7.5 ns/9 ns
Charge injection (Q _C)	6 pC
Bandwidth (BW)	150 MHz
OFF isolation (O _{ISO})	-62 dB at 1 MHz
Crosstalk (X _{TALK})	-85 dB at 1 MHz
Total harmonic distortion (THD)	0.005%
Leakage current (I _{COM(OFF)})	±20 nA
Power-supply current (I ₊)	0.1 μΑ
Dealers entire	8-pin VSSOP
Package option	8-pin YZP

(1) $V_+ = 5 V$, $T_A = 25$ °C

FUNCTION TABLE

IN	NC TO COM, COM TO NC
L	ON
Н	OFF

Absolute Maximum Ratings (1) (2)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V ₊	Supply voltage range ⁽³⁾		-0.5	6.5	V
$V_{NC} V_{COM}$	Analog voltage range ⁽³⁾ (4) (5)		-0.5	V ₊ + 0.5	V
I _K	Analog port diode current	V_{NC} , $V_{COM} < 0$	-50		mA
I _{NC}	On-state switch current	V V 045 V	-200	200	A
I _{COM}	On-state peak switch current ⁽⁶⁾	V_{NC} , $V_{COM} = 0$ to V_+	-400	400	mA
VI	Digital input voltage range (3) (4)	·	-0.5	6.5	V
I _{IK}	Digital clamp current	V _I < 0	-50		mA
I ₊	Continuous current through V+	,		100	mA
I _{GND}	Continuous current through GND		-100	100	mA
		DCT package		220	
θ_{JA}	Package thermal impedance ⁽⁷⁾	DCU package		227	°C/W
		YZP package		102	
T _{stg}	Storage temperature range		-65	150	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
- (3) All voltages are with respect to ground, unless otherwise specified.
- 4) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (5) This value is limited to 5.5 V maximum.
- (6) Pulse at 1-ms duration < 10% duty cycle.
- (7) The package thermal impedance is calculated in accordance with JESD 51-7.

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Electrical Characteristics for 5-V Supply⁽¹⁾

 $V_{+} = 4.5 \text{ V}$ to 5.5 V, $T_{A} = -40^{\circ}\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDIT	TIONS	T_A	V ₊	MIN	TYP	MAX	UNIT
Analog Switch								·	
Analog signal range	V _{COM} , V _{NC}					0		V ₊	V
Peak ON resistance	r .	$0 \le V_{NC} \le V_+$	Switch ON,	25°C	4.5 V		0.9	1.1	Ω
Teak ON Tesistance	r _{peak}	$I_{COM} = -100 \text{ mA},$	See Figure 13	Full	4.5 V			1.2	22
ON-state resistance	r _{on}	$V_{NC} = 2.5 V,$	Switch ON,	25°C	4.5 V		0.75	0.9	Ω
ON state resistance	ion	$I_{COM} = -100 \text{ mA},$	See Figure 13	Full	4.0 V			1	32
ON-state resistance	Δ.,	$V_{NC} = 2.5 V$	Switch ON,	25°C	45.1/		0.04	0.1	0
match between channels	Δr_{on}	$I_{COM} = -100 \text{ mA},$	See Figure 13	Full	4.5 V			0.1	Ω
ON-state resistance		$0 \le V_{NC} \le V_+,$ $I_{COM} = -100 \text{ mA},$	Switch ON, See Figure 13	25°C			0.2		
flatness	r _{on(flat)}	V _{NC} = 1 V, 1.5 V, 2.5 V,	Switch ON,	25°C	4.5 V		0.15	0.25	Ω
		$I_{COM} = -100 \text{ mA},$	See Figure 13	Full				0.25	
		V _{NC} = 1 V,		25°C		0 V	4	20	
NC OFF leakage current	I _{NC(OFF)}	$\begin{split} &V_{COM} = 4.5 \text{ V},\\ &\text{or}\\ &V_{NC} = 4.5 \text{ V},\\ &V_{COM} = 1 \text{ V}, \end{split}$	Switch OFF, See Figure 14	Full	5.5 V	-150		150	nA
		$V_{NC} = 0 \text{ to } 5.5 \text{ V},$	Switch OFF,	25°C	0.1/	-10 0.2	2 10		
	I _{NC(PWROFF)}	$V_{COM} = 5.5 \text{ V to } 0,$	See Figure 14	Full	0 V	-50		50	μΑ
		$V_{COM} = 1 V$,		25°C		0 V	4	20	
COM OFF leakage current	I _{COM(OFF)}	$V_{NC} = 4.5 \text{ V},$ or $V_{COM} = 4.5 \text{ V},$ $V_{NC} = 1 \text{ V},$	Switch OFF, See Figure 14	Full	5.5 V	-150		150	nA
	1	$V_{COM} = 0 \text{ to } 5.5 \text{ V},$	Switch OFF,	25°C	0 V	-10	0.2	10	
	I _{COM(PWROFF)}	$V_{NC} = 5.5 \text{ V to 0},$	See Figure 14	Full	0 0	-50		50	μA
		$V_{NC} = 1 V$		25°C		- 5	0.4	5	
NC ON leakage current	I _{NC(ON)}	$V_{COM} = Open,$ or $V_{NC} = 4.5 \text{ V},$ $V_{COM} = Open,$	Switch ON, See Figure 15	Full	5.5 V	-50		50	nA
		$V_{COM} = 1 V$,		25°C		-5	0.4	5	
COM ON leakage current	I _{COM(ON)}	V_{NC} = Open, or V_{COM} = 4.5 V, V_{NC} = Open,	Switch ON, See Figure 15	Full	Full 5.5 V	-50		50	nA
Digital Control Input	s (IN1, IN2) ⁽²⁾								
Input logic high	V _{IH}			Full		2.4		5.5	V
Input logic low	V _{IL}			Full		0		8.0	V
Input leakage	I _{IH} , I _{IL}	V _I = 5.5 V or 0		25°C	5.5 V	-2	0.3	2	nA
current	'IH, 'IL	v ₁ = 0.0 v 01 0		Full	J.J V	-20		20	ш

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The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum All unused digital inputs of the device must be held at V_{+} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



Electrical Characteristics for 5-V Supply⁽¹⁾ (continued)

 $V_{+} = 4.5 \text{ V}$ to 5.5 V, $T_{A} = -40^{\circ}\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST C	ONDITIONS	T _A	V+	MIN	TYP	MAX	UNIT
Dynamic				•	•				
		V V	0 25 - 5	25°C	5 V	1	4.5	7.5	
Turn-on time	t _{ON}	$V_{COM} = V_+,$ $R_L = 50 \Omega,$	C _L = 35 pF, See Figure 17	Full	4.5 V to 5.5 V	1		9	ns
		., .,	0 05 5	25°C	5 V	4.5	8	11	
Turn-off time	t _{OFF}	$V_{COM} = V_+,$ $R_L = 50 \Omega,$	C _L = 35 pF, See Figure 17	Full	4.5 V to 5.5 V	3.5		13	ns
Charge injection	Q _C	$V_{GEN} = 0,$ $R_{GEN} = 0$,	C _L = 1 nF, See Figure 21	25°C	5 V		6		рС
NC OFF capacitance	C _{NC(OFF)}	$V_{NC} = V_{+}$ or GND, Switch OFF,	See Figure 16	25°C	5 V		19		pF
COM OFF capacitance	C _{COM(OFF)}	V _{COM} = V ₊ or GND, Switch OFF,	See Figure 16	25°C	5 V		18		pF
NC ON capacitance	C _{NC(ON)}	$V_{NC} = V_{+}$ or GND, Switch ON,	See Figure 16	25°C	5 V		35.5		pF
COM ON capacitance	C _{COM(ON)}	V _{COM} = V ₊ or GND, Switch ON,	See Figure 16	25°C	5 V		35.5		pF
Digital input capacitance	C _I	$V_I = V_+ \text{ or GND},$	See Figure 16	25°C	5 V		2		pF
Bandwidth	BW	$R_L = 50 \Omega$, Switch ON,	See Figure 18	25°C	5 V		150		MHz
OFF isolation	O _{ISO}	$R_L = 50 \Omega$, f = 1 MHz,	Switch OFF, See Figure 19	25°C	5 V		-62		dB
Crosstalk	X _{TALK}	$R_L = 50 \Omega$, f = 1 MHz,	Switch ON, See Figure 20	25°C	5 V		-85		dB
Total harmonic distortion	THD	$R_L = 600 \Omega,$ $C_L = 50 pF,$	f = 20 Hz to 20 kHz, See Figure 22	25°C	5 V		0.00		%
Supply				•	•				
Positive supply		V V or CND	Switch ON or OFF	25°C	5.5 V		0.01	0.1	
current	I ₊	$V_I = V_+ \text{ or GND},$	SWILCTI ON OF OFF	Full	5.5 V			1	μΑ

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

Electrical Characteristics for 3.3-V Supply⁽¹⁾

 $V_{+} = 3 \text{ V to } 3.6 \text{ V}, T_{A} = -40^{\circ}\text{C to } 85^{\circ}\text{C} \text{ (unless otherwise noted)}$

PARAMETER	SYMBOL	TEST CON	DITIONS	T_A	V ₊	MIN	TYP	MAX	UNIT
Analog Switch								·	
Analog signal range	V _{COM} , V _{NC}					0		V ₊	V
Peak ON resistance	r _{peak}	$0 \le V_{NC} \le V_{+},$ $I_{COM} = -100 \text{ mA},$	Switch ON, See Figure 13	25°C Full	3 V		1.3	1.6 1.8	Ω
ON-state resistance	r _{on}	$V_{NC} = 2 V,$ $I_{COM} = -100 \text{ mA},$	Switch ON, See Figure 13	25°C Full	3 V		1.1	1.5 1.7	Ω
ON-state resistance match between	Δr_{on}	V _{NC} = 2 V, 0.8 V, I _{COM} = -100 mA,	Switch ON, See Figure 13	25°C Full	3 V		0.04	0.1	Ω
channels		$0 \le V_{NC} \le V_{+},$ $I_{COM} = -100 \text{ mA},$	Switch ON, See Figure 13	25°C			0.3	0.1	
ON-state resistance flatness	r _{on(flat)}	V _{NC} = 2 V, 0.8 V, I _{COM} = -100 mA,	Switch ON, See Figure 13	25°C Full	3 V		0.15	0.25 0.25	Ω
		$V_{NC} = 1 V$	3	25°C		- 5	0.5	5	
NC OFF leakage current	I _{NC(OFF)}	V _{COM} = 3 V, or V _{NC} = 3 V, V _{COM} = 1 V,	Switch OFF, See Figure 14	Full	3.6 V	-50	0.0	50	nA
		$V_{NC} = 0 \text{ to } 3.6 \text{ V},$	Switch OFF,	25°C	0 V	-5	0.1	5	
	I _{NC(PWROFF)}	$V_{COM} = 3.6 \text{ V to 0},$ See Figure 14	See Figure 14	Full	0 0	-25		25	μA
		$V_{COM} = 1 V$,		25°C		- 5	0.5	5	
COM OFF leakage current	I _{COM(OFF)}	$V_{NC} = 3 V$, or $V_{COM} = 3 V$, $V_{NC} = 1 V$,	Switch OFF, See Figure 14	Full	3.6 V	-50		50	nA
		$V_{COM} = 0 \text{ to } 3.6 \text{ V},$	Switch OFF,	25°C	0 V	- 5	0.1	5	
	ICOM(PWROFF)	$V_{NC} = 3.6 \text{ V to 0},$	See Figure 14	Full	U V	-25		25	μA
		$V_{NC} = 1 V$,		25°C		-2	0.3	2	
NC ON leakage current	I _{NC(ON)}	$V_{COM} = Open,$ or $V_{NC} = 3 V,$ $V_{COM} = Open,$	Switch ON, See Figure 15	Full	3.6 V	-20		20	nA
		$V_{COM} = 1 V$,		25°C		-2	0.3	2	
COM ON leakage current	$V_{NC} = Open,$ Switch ON,	Full	3.6 V	-20		20	nA		
Digital Control Inputs	(IN1, IN2) ⁽²⁾								
Input logic high	V _{IH}			Full		2		5.5	V
Input logic low	V _{IL}			Full		0		8.0	V
Input leakage current	I _{IH} , I _{IL}	V _I = 5.5 V or 0		25°C	3.6 V	-2	0.3	2	nA

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The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum All unused digital inputs of the device must be held at V_{+} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



Electrical Characteristics for 3.3-V Supply⁽¹⁾ (continued)

 $V_{+} = 3 \text{ V to } 3.6 \text{ V}, T_{A} = -40^{\circ}\text{C to } 85^{\circ}\text{C} \text{ (unless otherwise noted)}$

PARAMETER	SYMBOL	TEST CO	ONDITIONS	T_A	V+	MIN	TYP	MAX	UNIT
Dynamic									
		V V	C 25 pF	25°C	3.3 V	1.5	5	9.5	
Turn-on time	t _{ON}	$V_{COM} = V_+,$ $R_L = 50 \Omega,$	C _L = 35 pF, See Figure 17	Full	3 V to 3.6 V	1.0		10	ns
		V V	0 25 -5	25°C	3.3 V	4.5	8.5	11	
Turn-off time	t _{OFF}	$V_{COM} = V_+,$ $R_L = 50 \Omega,$	C _L = 35 pF, See Figure 17	Full	3 V to 3.6 V	3		12.5	ns
Charge injection	Q _C	$V_{GEN} = 0,$ $R_{GEN} = 0,$	C _L = 1 nF, See Figure 21	25°C	3.3 V		6		рС
NC OFF capacitance	C _{NC(OFF)}	V _{NC} = V ₊ or GND, Switch OFF,	See Figure 16	25°C	3.3 V		19.5		pF
COM OFF capacitance	C _{COM(OFF)}	V _{COM} = V ₊ or GND, Switch OFF,	See Figure 16	25°C	3.3 V		18.5		pF
NC ON capacitance	C _{NC(ON)}	V _{NC} = V ₊ or GND, Switch ON,	See Figure 16	25°C	3.3 V		36		pF
COM ON capacitance	C _{COM(ON)}	V _{COM} = V ₊ or GND, Switch ON,	See Figure 16	25°C	3.3 V		36		pF
Digital input capacitance	Cı	$V_I = V_+ \text{ or GND},$	See Figure 16	25°C	3.3 V		2		pF
Bandwidth	BW	$R_L = 50 \Omega$, Switch ON,	See Figure 18	25°C	3.3 V		150		MHz
OFF isolation	O _{ISO}	$R_L = 50 \Omega$, f = 1 MHz,	Switch OFF, See Figure 19	25°C	3.3 V		-62		dB
Crosstalk	X _{TALK}	$R_L = 50 \Omega$, f = 1 MHz,	Switch ON, See Figure 20	25°C	3.3 V		-85		dB
Total harmonic distortion	THD	$R_L = 600 \Omega,$ $C_L = 50 pF,$	f = 20 Hz to 20 kHz, See Figure 22	25°C	3.3 V		0.01		%
Supply	•		-		•				
Positive supply		V – V or CND	Switch ON or OFF	25°C	261/		0.001	0.05	
current	I ₊	$V_I = V_+ \text{ or GND},$	Switch ON or OFF	Full	3.6 V			0.3	μΑ

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

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Electrical Characteristics for 2.5-V Supply⁽¹⁾

 $V_{+} = 2.3 \text{ V}$ to 2.7 V, $T_{A} = -40^{\circ}\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CON	DITIONS	T _A	V ₊	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V _{COM} , V _{NC}				2.3 V	0		V ₊	V
Peak ON resistance	r _{peak}	$0 \le V_{NC} \le V_+,$ $I_{COM} = -100 \text{ mA},$	Switch ON, See Figure 13	25°C Full	2.3 V		1.8	2.4 2.6	Ω
ON-state resistance	r _{on}	$V_{NC} = 2 V,$ $I_{COM} = -100 \text{ mA},$	Switch ON, See Figure 13	25°C Full	2.3 V		1.2	2.1	Ω
ON-state resistance match between	Δr _{on}	$V_{NC} = 2 \text{ V}, 0.8 \text{ V},$ $I_{COM} = -100 \text{ mA},$	Switch ON, See Figure 13	25°C Full	2.3 V		0.04	0.15	Ω
channels		$0 \le V_{NC} \le V_{+},$ $I_{COM} = -100 \text{ mA},$	Switch ON, See Figure 13	25°C			0.7	0.13	
ON-state resistance flatness	r _{on(flat)}	$V_{NC} = 2 \text{ V}, 0.8 \text{ V},$ $I_{COM} = -100 \text{ mA},$	Switch ON, See Figure 13	25°C Full	2.3 V		0.4	0.6	Ω
		$V_{NC} = 1 \text{ V},$	Coo'r igaro ro	25°C		-5	0.3	5	
NC OFF leakage current	I _{NC(OFF)}	$V_{COM} = 3 V$, or $V_{NC} = 3 V$, $V_{COM} = 1 V$,	Switch OFF, See Figure 14	Full	2.7 V	-50	0.0	50	nA
	I _{NC(PWROFF)}	$V_{NC} = 0 \text{ to } 3.6 \text{ V},$ $V_{COM} = 3.6 \text{ V to } 0,$	Switch OFF, See Figure 14	25°C Full	0 V	-2 -15	0.05	2 15	μΑ
		V _{COM} = 1 V,		25°C		-5	0.3	5	
COM OFF leakage current	I _{COM(OFF)}	$V_{NC} = 3 \text{ V},$ or $V_{COM} = 3 \text{ V},$ $V_{NC} = 1 \text{ V},$	Switch OFF, See Figure 14	Full	2.7 V	-50		50	nA
	I _{COM(PWROFF)}	$V_{COM} = 0 \text{ to } 3.6 \text{ V},$ $V_{NC} = 3.6 \text{ V to } 0,$	Switch OFF, See Figure 14	25°C Full	0 V	-2 -15	0.05	2 15	μΑ
		$V_{NC} = 1 V$		25°C		-2	0.3	2	
NC ON leakage current	I _{NC(ON)}	$V_{COM} = Open,$ or $V_{NC} = 3 V,$ $V_{COM} = Open,$	Switch ON, See Figure 15	Full	2.7 V	-20	0.0	20	nA
		V _{COM} = 1 V, V _{NC} = Open,	0 11 011	25°C		-2	0.3	2	
COM ON leakage current	I _{COM(ON)}	v _{NC} = Open, Switch ON, or See Figure 1 V _{COM} = 3 V, See Figure 1		Full	2.7 V	-20		20	nA
Digital Control Inputs	(IN1, IN2) ⁽²⁾	1		ı		1			
Input logic high	V _{IH}			Full		1.8		5.5	V
Input logic low	V _{IL}		_	Full		0		0.6	V
	<u> </u>			25°C	_	-2	0.3	2	

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

 ⁽²⁾ All unused digital inputs of the device must be held at V₊ or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



Electrical Characteristics for 2.5-V Supply⁽¹⁾ (continued)

 $V_{+} = 2.3 \text{ V}$ to 2.7 V, $T_{A} = -40^{\circ}\text{C}$ to 85°C (unless otherwise noted)

SYMBOL	TEST CC	ONDITIONS	T_A	V+	MIN	TYP	MAX	UNIT
•								
	V V	0 25 75	25°C	2.5 V	2	6	10	
t _{ON}	$R_L = 50 \Omega$	See Figure 17	Full	2.3 V to 2.7 V	1		12	ns
	\/ \/	0 25 - 5	25°C	2.5 V	4.5	8	12.5	
t _{OFF}	$V_{COM} = V_+,$ $R_L = 50 \Omega,$	See Figure 17	Full	2.3 V to 2.7 V	3		15	ns
Q _C	$V_{GEN} = 0,$ $R_{GEN} = 0,$	$C_L = 1 \text{ nF},$ See Figure 21	25°C	2.5 V		4		рС
C _{NC(OFF)}	V _{NC} = V ₊ or GND, Switch OFF,	See Figure 16	25°C	2.5 V		19.5		pF
C _{COM(OFF)}	$V_{COM} = V_{+}$ or GND, Switch OFF,	See Figure 16	25°C	2.5 V		18.5		pF
C _{NC(ON)}	V _{NC} = V ₊ or GND, Switch ON,	See Figure 16	25°C	2.5 V		36.5		pF
C _{COM(ON)}	V _{COM} = V ₊ or GND, Switch ON,	See Figure 16	25°C	2.5 V		36.5		pF
Cı	$V_I = V_+ \text{ or GND},$	See Figure 16	25°C	2.5 V		2		pF
BW	$R_L = 50 \Omega$, Switch ON,	See Figure 18	25°C	2.5 V		150		MHz
O _{ISO}	$R_L = 50 \Omega$, f = 1 MHz,	Switch OFF, See Figure 19	25°C	2.5 V		-62		dB
X _{TALK}	$R_L = 50 \Omega$, f = 1 MHz,	Switch ON, See Figure 20	25°C	3.3 V		-85		dB
THD	$R_L = 600 \Omega,$ $C_L = 50 pF,$	f = 20 Hz to 20 kHz, See Figure 22	25°C	2.5 V		0.02		%
•		-		•				
I ₊	$V_1 = V_+ \text{ or GND},$	Switch ON or OFF	25°C	2.7 V		0.001	0.02	μA
	ton toff Qc Cnc(off) Ccom(off) Com(on) Ci BW Oiso Xtalk THD	$t_{ON} \qquad V_{COM} = V_{+}, \\ R_{L} = 50 \ \Omega, \\$ $t_{OFF} \qquad V_{COM} = V_{+}, \\ R_{L} = 50 \ \Omega, \\$ $Q_{C} \qquad V_{GEN} = 0, \\ R_{GEN} = 0, \\$ $C_{NC(OFF)} \qquad V_{NC} = V_{+} \text{ or GND, Switch OFF,} \\$ $C_{COM(OFF)} \qquad V_{COM} = V_{+} \text{ or GND, Switch ON,} \\$ $C_{COM(ON)} \qquad V_{NC} = V_{+} \text{ or GND, Switch ON,} \\$ $C_{COM(ON)} \qquad V_{COM} = V_{+} \text{ or GND, Switch ON,} \\$ $C_{I} \qquad V_{I} = V_{+} \text{ or GND,} \\$ $BW \qquad R_{L} = 50 \ \Omega, \\ Switch ON, \\$ $O_{ISO} \qquad R_{L} = 50 \ \Omega, \\ f = 1 \ MHz, \\$ $X_{TALK} \qquad R_{L} = 600 \ \Omega, \\ C_{L} = 50 \ pF, \\$	$t_{ON} \begin{cases} V_{COM} = V_{+}, & C_{L} = 35 \text{ pF}, \\ R_{L} = 50 \Omega, & \text{See Figure 17} \end{cases}$ $t_{OFF} \begin{cases} V_{COM} = V_{+}, & C_{L} = 35 \text{ pF}, \\ R_{L} = 50 \Omega, & \text{See Figure 17} \end{cases}$ $Q_{C} \begin{cases} V_{GEN} = 0, & C_{L} = 1 \text{ nF}, \\ R_{GEN} = 0, & \text{See Figure 21} \end{cases}$ $C_{NC(OFF)} \begin{cases} V_{NC} = V_{+} \text{ or GND}, \\ Switch \text{ OFF}, & \text{See Figure 16} \end{cases}$ $C_{COM(OFF)} \begin{cases} V_{COM} = V_{+} \text{ or GND}, \\ Switch \text{ OFF}, & \text{See Figure 16} \end{cases}$ $C_{NC(ON)} \begin{cases} V_{NC} = V_{+} \text{ or GND}, \\ Switch \text{ ON}, & \text{See Figure 16} \end{cases}$ $C_{COM(ON)} \begin{cases} V_{COM} = V_{+} \text{ or GND}, \\ Switch \text{ ON}, & \text{See Figure 16} \end{cases}$ $C_{COM(ON)} \begin{cases} V_{COM} = V_{+} \text{ or GND}, \\ Switch \text{ ON}, & \text{See Figure 16} \end{cases}$ $C_{I} V_{I} = V_{+} \text{ or GND}, & \text{See Figure 16} \end{cases}$ $R_{L} = 50 \Omega, & \text{Switch OFF}, \\ See \text{ Figure 19} \end{cases}$ $X_{TALK} \begin{cases} R_{L} = 50 \Omega, \\ f = 1 \text{ MHz}, & \text{See Figure 20} \end{cases}$ $THD \begin{cases} R_{L} = 600 \Omega, \\ C_{L} = 50 \text{ pF}, & \text{See Figure 22} \end{cases}$	$t_{ON} \begin{array}{c} V_{COM} = V_{+}, \\ R_{L} = 50 \ \Omega, \\ \end{array} \begin{array}{c} C_{L} = 35 \ \text{pF}, \\ \text{See Figure 17} \\ \end{array} \begin{array}{c} 25^{\circ}\text{C} \\ \end{array}$	$t_{ON} \begin{array}{c} V_{COM} = V_{+}, \\ R_L = 50 \ \Omega, \end{array} \begin{array}{c} C_L = 35 \ pF, \\ See \ Figure \ 17 \end{array} \qquad \begin{array}{c} 25^{\circ}C \\ Full \end{array} \begin{array}{c} 2.3 \ V \ to \\ 2.3 \ V \ to \\ 2.7 \ V \\ \end{array}$ $t_{OFF} \begin{array}{c} V_{COM} = V_{+}, \\ R_L = 50 \ \Omega, \end{array} \begin{array}{c} C_L = 35 \ pF, \\ See \ Figure \ 17 \end{array} \qquad \begin{array}{c} 25^{\circ}C \\ \end{array} \begin{array}{c} 2.3 \ V \ to \\ 2.7 \ V \\ \end{array}$ $Q_C \begin{array}{c} V_{GEN} = 0, \\ R_{GEN} = 0, \end{array} \begin{array}{c} C_L = 1 \ nF, \\ See \ Figure \ 21 \end{array} \qquad \begin{array}{c} 25^{\circ}C \\ \end{array} \begin{array}{c} 2.5 \ V \\ \end{array}$ $C_{NC(OFF)} \begin{array}{c} V_{NC} = V_{+} \ or \ GND, \\ Switch \ OFF, \end{array} \begin{array}{c} See \ Figure \ 16 \\ \end{array} \begin{array}{c} 25^{\circ}C \\ \end{array} \begin{array}{c} 2.5 \ V \\ \end{array}$ $C_{COM(OFF)} \begin{array}{c} V_{COM} = V_{+} \ or \ GND, \\ Switch \ OFF, \end{array} \begin{array}{c} See \ Figure \ 16 \\ \end{array} \begin{array}{c} 25^{\circ}C \\ \end{array} \begin{array}{c} 2.5 \ V \\ \end{array}$ $C_{COM(OF)} \begin{array}{c} V_{NC} = V_{+} \ or \ GND, \\ Switch \ ON, \end{array} \begin{array}{c} See \ Figure \ 16 \\ \end{array} \begin{array}{c} 25^{\circ}C \\ \end{array} \begin{array}{c} 2.5 \ V \\ \end{array}$ $C_{COM(ON)} \begin{array}{c} V_{NC} = V_{+} \ or \ GND, \\ Switch \ ON, \end{array} \begin{array}{c} See \ Figure \ 16 \\ \end{array} \begin{array}{c} 25^{\circ}C \\ \end{array} \begin{array}{c} 2.5 \ V \\ \end{array}$ $C_{I} V_{I} = V_{+} \ or \ GND, \qquad See \ Figure \ 16 \\ \end{array} \begin{array}{c} 25^{\circ}C \\ \end{array} \begin{array}{c} 2.5 \ V \\ \end{array}$ $P_{I} = 50 \ \Omega, \qquad See \ Figure \ 16 \\ \end{array} \begin{array}{c} See \ Figure \ 16 \\ \end{array} \begin{array}{c} 25^{\circ}C \\ \end{array} \begin{array}{c} 2.5 \ V \\ \end{array}$ $P_{I} = 1 \ MHz, \qquad See \ Figure \ 18 \\ \end{array} \begin{array}{c} 25^{\circ}C \\ \end{array} \begin{array}{c} 2.5 \ V \\ \end{array}$ $P_{I} = 1 \ MHz, \qquad See \ Figure \ 19 \\ \end{array} \begin{array}{c} 25^{\circ}C \\ \end{array} \begin{array}{c} 2.5 \ V \\ \end{array}$ $P_{I} = 1 \ MHz, \qquad See \ Figure \ 20 \\ \end{array} \begin{array}{c} 25^{\circ}C \\ \end{array} \begin{array}{c} 2.5 \ V \\ \end{array}$	$t_{ON} \begin{array}{c} V_{COM} = V_{+}, \\ R_{L} = 50 \; \Omega, \\ \end{array} \begin{array}{c} C_{L} = 35 \; \text{pF}, \\ \text{See Figure 17} \\ \end{array} \begin{array}{c} 25^{\circ}\text{C} \\ \end{array} \begin{array}{c} 2.5 \; \text{V} \\ \end{array} \begin{array}{c} 2 \\ \end{array} \begin{array}{c} 2 \\ \end{array} \begin{array}{c} V_{COM} = V_{+}, \\ R_{L} = 50 \; \Omega, \\ \end{array} \begin{array}{c} C_{L} = 35 \; \text{pF}, \\ \text{See Figure 17} \\ \end{array} \begin{array}{c} 25^{\circ}\text{C} \\ \end{array} \begin{array}{c} 2.3 \; \text{V to} \\ 2.7 \; \text{V} \\ \end{array} \begin{array}{c} 1 \\ \end{array} \begin{array}{c} 2.3 \; \text{V to} \\ \end{array} \begin{array}{c} 2.7 \; \text{V} \\ \end{array} \begin{array}{c} 3 \\ \end{array} \begin{array}{c} 2.5 \; \text{C} \\ \end{array} \begin{array}{c} 2.5 \; \text{V} \\ \end{array} $	$t_{ON} \begin{array}{c} V_{COM} = V_{+}, \\ R_{L} = 50 \ \Omega, \\ \end{array} \begin{array}{c} C_{L} = 35 \ pF, \\ See \ Figure \ 17 \\ \end{array} \begin{array}{c} 25^{\circ}C \\ \end{array} \begin{array}{c} 2.5 \ V \\ \end{array} \begin{array}{c} 2 \ 6 \\ \end{array} \\ Full \\ \end{array} \begin{array}{c} 2.3 \ V \ to \\ 2.7 \ V \\ \end{array} \begin{array}{c} 1 \\ \end{array} \\ \end{array} \begin{array}{c} V_{COM} = V_{+}, \\ R_{L} = 50 \ \Omega, \\ \end{array} \begin{array}{c} C_{L} = 35 \ pF, \\ See \ Figure \ 17 \\ \end{array} \begin{array}{c} 25^{\circ}C \\ \end{array} \begin{array}{c} 2.5 \ V \\ \end{array} \begin{array}{c} 4.5 8 \\ \end{array} \\ \end{array} \begin{array}{c} V_{COM} = V_{+}, \\ R_{L} = 50 \ \Omega, \\ \end{array} \begin{array}{c} C_{L} = 35 \ pF, \\ See \ Figure \ 17 \\ \end{array} \begin{array}{c} 25^{\circ}C \\ \end{array} \begin{array}{c} 2.5 \ V \\ \end{array} \begin{array}{c} 4.5 8 \\ \end{array} \begin{array}{c} 2.3 \ V \ to \\ \end{array} \begin{array}{c} 3 \\ \end{array} \begin{array}{c} 2.5 \ V \\ \end{array} \begin{array}{c} 4.5 8 \\ \end{array} \begin{array}{c} 2.5 \ V \\ \end{array} \begin{array}{c} 2.5 \ V \\ \end{array} \begin{array}{c} 4.5 V \\ \end{array} \begin{array}{c} 2.5 \ V$	$t_{ON} \begin{array}{c} V_{COM} = V_{+}, \\ R_{L} = 50 \ \Omega, \\ R_{L} = 50 \ \Omega, \\ \end{array} \begin{array}{c} C_{L} = 35 \ \text{pF}, \\ See \ \text{Figure 17} \\ \end{array} \begin{array}{c} 25^{\circ}\text{C} \\ \end{array} \begin{array}{c} 2.5 \ \text{V} \\ \end{array} \begin{array}{c} 2 \ \text{o} \\ \end{array} \begin{array}{c} 0 \ \text{o} \\ \end{array} \begin{array}{c} V_{COM} = V_{+}, \\ R_{L} = 50 \ \Omega, \\ \end{array} \begin{array}{c} C_{L} = 35 \ \text{pF}, \\ See \ \text{Figure 17} \\ \end{array} \begin{array}{c} 25^{\circ}\text{C} \\ \end{array} \begin{array}{c} 2.5 \ \text{V} \\ \end{array} \begin{array}{c} 4.5 \ \text{B} 12.5 \\ \end{array} \begin{array}{c} 2.3 \ \text{V to} \\ \end{array} \begin{array}{c} 3 \ \text{mod} \\ \end{array} \begin{array}{c} 3 \ \text{mod} \\ \end{array} \begin{array}{c} 2.3 \ \text{V to} \\ \end{array} \begin{array}{c} 3 \ \text{mod} \\ \end{array} \begin{array}{c} 3 \ \text{mod} \\ \end{array} \begin{array}{c} 2.3 \ \text{V to} \\ \end{array} \begin{array}{c} 3 \ \text{mod} \\ \end{array} \begin{array}{c} 3 \ \text{mod} \\ \end{array} \begin{array}{c} 3 \ \text{mod} \\ \end{array} \begin{array}{c} 1.5 \ \text{mod} \\ \end{array} \begin{array}{c} 2.3 \ \text{V to} \\ \end{array} \begin{array}{c} 3 \ \text{mod} \\ \end{array} $

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

Electrical Characteristics for 1.8-V Supply⁽¹⁾

 $V_{+} = 1.65 \text{ V}$ to 1.95 V, $T_{A} = -40 ^{\circ}\text{C}$ to 85°C (unless otherwise noted))

PARAMETER	SYMBOL	TEST CON	DITIONS	T_A	V ₊	MIN	TYP	MAX	UNIT	
Analog Switch										
Analog signal range	V _{COM} , V _{NC}					0		V ₊	V	
Peak ON resistance	r .	$0 \le V_{NC} \le V_+$	Switch ON,	25°C	1.65 V		4.2	25	Ω	
Teak ON Tesistance	r _{peak}	$I_{COM} = -100 \text{ mA},$	See Figure 13	Full	1.05 V			30		
ON-state resistance	r _{on}	$V_{NC} = 2 V$,	Switch ON,	25°C	1.65 V		1.6	3.9	Ω	
OIV state resistance	ion	$I_{COM} = -100 \text{ mA},$	See Figure 13	Full	1.00 V			4.0	32	
ON-state resistance	Δ.,	$V_{NC} = 2 \text{ V}, 0.8 \text{ V},$	Switch ON,	25°C	4.05.1/		0.04	0.2	•	
match between channels	Δr _{on}	$I_{COM} = -100 \text{ mA},$	See Figure 13	Full	1.65 V			0.2	Ω	
ON-state resistance		$0 \le V_{NC} \le V_{+},$ $I_{COM} = -100 \text{ mA},$	Switch ON, See Figure 13	25°C			2.8			
flatness	r _{on(flat)}	$V_{NC} = 2 V, 0.8 V,$	Switch ON,	25°C	1.65 V		4.1	22	Ω	
		$I_{COM} = -100 \text{ mA},$	See Figure 13	Full				27		
		$V_{NC} = 1 V$,		25°C		- 5		5		
NC OFF leakage current	I _{NC(OFF)}	$V_{COM} = 3 \text{ V},$ or $V_{NC} = 3 \text{ V},$ $V_{COM} = 1 \text{ V},$	Switch OFF, See Figure 14	Full	1.95 V	-50		50	nA	
-			$V_{NC} = 0 \text{ to } 3.6 \text{ V},$	Switch OFF,	25°C	0 V	-2		2	
	I _{NC(PWROFF)}	$V_{COM} = 3.6 \text{ V to 0},$ See Figure 14	Full	0 0	-10		10	μA		
		$V_{COM} = 1 V$		25°C		-5		5		
COM OFF leakage current	I _{COM(OFF)}	$\begin{aligned} &V_{NC}=3\ V,\\ ∨\\ &V_{COM}=3\ V,\\ &V_{NC}=1\ V, \end{aligned}$	Switch OFF, See Figure 14	Full	1.95 V	– 50		50	nA	
	1	$V_{COM} = 0 \text{ to } 3.6 \text{ V},$	Switch OFF,	25°C	0 V	-2		2	μA	
	ICOM(PWROFF)	$V_{NC} = 3.6 \text{ V to 0},$	See Figure 14	Full	U V	-10		10	μΑ	
		$V_{NC} = 1 V$		25°C		-2		2		
NC ON leakage current	I _{NC(ON)}	$V_{COM} = Open,$ or $V_{NC} = 3 V,$ $V_{COM} = Open,$	Switch ON, See Figure 15	Full	1.95 V	-20		20	nA	
		$V_{COM} = 1 V$		25°C		-2		2		
COM ON leakage current		Full	1.95 V	-20		20	nA			
Digital Control Inputs	(IN1, IN2) ⁽²⁾									
Input logic high	V _{IH}			Full		1.5		5.5	٧	
Input logic low	V _{IL}			Full		0		0.6	V	
Input leakage current	l., I.,	V _I = 5.5 V or 0		25°C	1.95 V	-2	0.3	2	nA	
input icanage currell	I _{IH} , I _{IL}	v ₁ = 3.3 v 01 0		Full	1.33 V	-20		20	II/A	

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The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum All unused digital inputs of the device must be held at V_{+} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



Electrical Characteristics for 1.8-V Supply⁽¹⁾ (continued)

 V_{+} = 1.65 V to 1.95 V, T_{A} = -40°C to 85°C (unless otherwise noted))

PARAMETER	SYMBOL	TEST CO	NDITIONS	T _A	V+	MIN	TYP	MAX	UNIT
Dynamic									
		$V_{COM} = V_+,$	$C_1 = 35 \text{ pF},$	25°C	1.8 V	3	9	18	
Turn-on time	t _{ON}	$R_L = 50 \Omega$	See Figure 17	Full	1.65 V to 1.95 V	1		20	ns
		$V_{COM} = V_+,$	$C_1 = 35 \text{ pF},$	25°C	1.8 V	5	10	15.5	
Turn-off time	t _{OFF}	$R_L = 50 \Omega$	See Figure 17	Full	1.65 V to 1.95 V	4		18.5	ns
Charge injection	$Q_{\mathbb{C}}$	$V_{GEN} = 0,$ $R_{GEN} = 0,$	$C_L = 1 \text{ nF},$ See Figure 21	25°C	1.8 V		2		рС
NC OFF capacitance	C _{NC(OFF)}	$V_{NC} = V_{+}$ or GND, Switch OFF,	See Figure 16	25°C	1.8 V		19.5		pF
COM OFF capacitance	C _{COM(OFF)}	V _{COM} = V ₊ or GND, Switch OFF,	See Figure 16	25°C	1.8 V		18.5		pF
NC ON capacitance	C _{NC(ON)}	V _{NC} = V ₊ or GND, Switch ON,	See Figure 16	25°C	1.8 V		36.5		pF
COM ON capacitance	C _{COM(ON)}	V _{COM} = V ₊ or GND, Switch ON,	See Figure 16	25°C	1.8 V		36.5		pF
Digital input capacitance	Cı	$V_I = V_+ \text{ or GND},$	See Figure 16	25°C	1.8 V		2		pF
Bandwidth	BW	$R_L = 50 \Omega$, Switch ON,	See Figure 18	25°C	1.8 V		150		MHz
OFF isolation	O _{ISO}	$R_L = 50 \Omega$, f = 1 MHz,	Switch OFF, See Figure 19	25°C	1.8 V		-62		dB
Crosstalk	X _{TALK}	$R_L = 50 \Omega$, f = 1 MHz,	Switch ON, See Figure 20	25°C	1.8 V		-85		dB
Total harmonic distortion	THD	$R_L = 600 \Omega,$ $C_L = 50 pF,$	f = 20 Hz to 20 kHz See Figure 22	25°C	1.8 V		0.05 5		%
Supply									
Positive supply	I ₊	$V_1 = V_+$ or GND,	Switch ON or OFF	25°C	1.95 V		0.00	0.01	μA
current	·			Full				0.15	•

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

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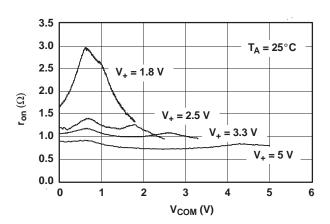


Figure 1. ron vs V_{COM}

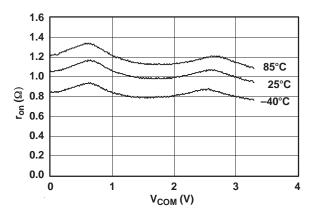


Figure 2. r_{on} vs V_{COM} ($V_{+} = 3.3 \text{ V}$)

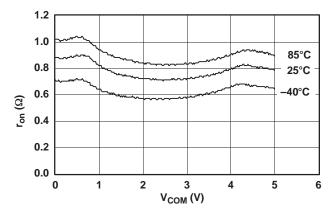


Figure 3. r_{on} vs V_{COM} ($V_{+} = 5$ V)



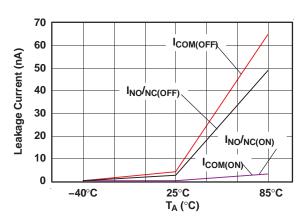


Figure 4. Leakage Current vs Temperature ($V_{+} = 5 \text{ V}$)

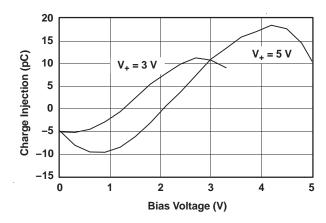


Figure 5. Charge Injection (Q_C) vs V_{COM}

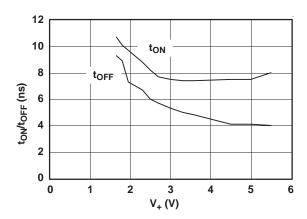


Figure 6. t_{ON} and t_{OFF} vs Supply Voltage



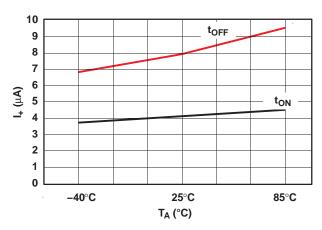


Figure 7. t_{ON} and t_{OFF} vs Temperature (V₊ = 5 V)

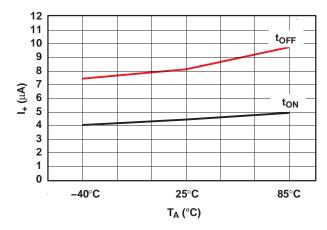


Figure 8. t_{ON} and t_{OFF} vs Temperature (V₊ = 5 V)

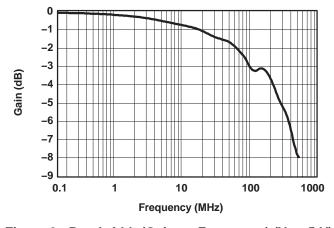


Figure 9. Bandwidth (Gain vs Frequency) ($V_{+} = 5 \text{ V}$)

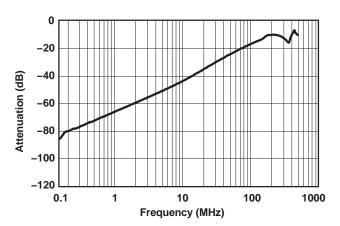


Figure 10. OFF Isolation vs Frequency

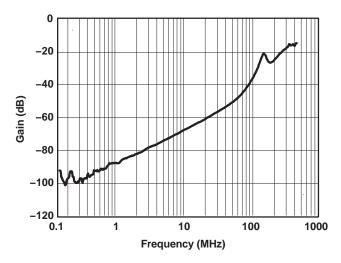


Figure 11. Gain vs Frequency

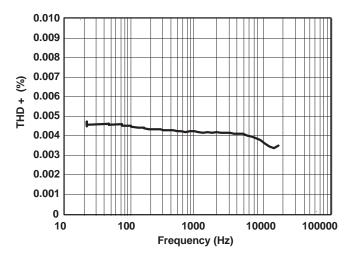


Figure 12. Total Harmonic Distortion vs Frequency $(V_{+} = 5 \text{ V})$



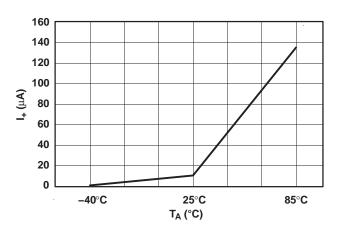


Figure 13. Power-Supply Current vs Temperature ($V_{+} = 5 \text{ V}$)

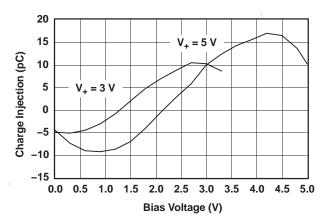


Figure 14. Charge Injection (Q_C) vs V_{COM}

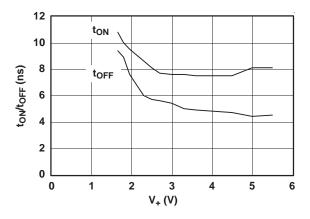


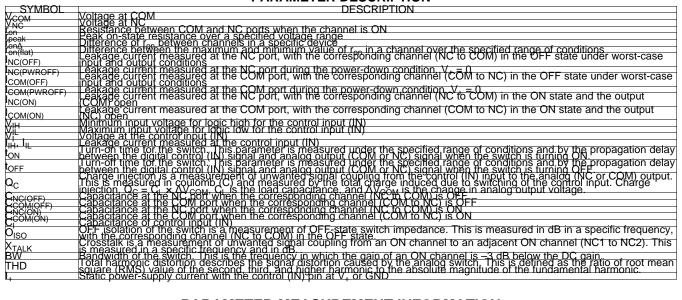
Figure 15. t_{ON} and t_{OFF} vs Supply Voltage



Table 1. PIN DESCRIPTION

PIN NUMBER	NAME	L DESCRIPTION
1	NAME COM1	Normally closed
2	COM1	Common
3	INI'2	Digital control pin to connect COM to NC
4	GND	Didital ground'.
5	Sič2	Normally closed
6	COM2	Common
1	IN1	Digital control pin to connect COM to NC
8	V ₊	Power Supply

PARAMETER DESCRIPTION



PARAMETER MEASUREMENT INFORMATION

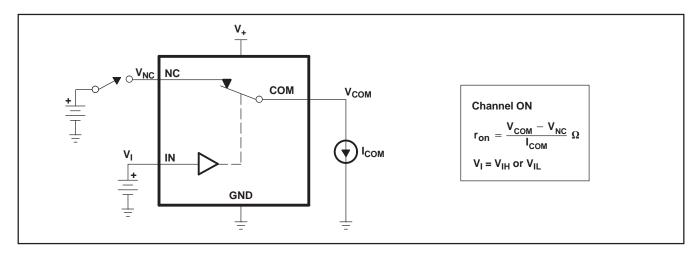


Figure 16. ON-State Resistance (ron)

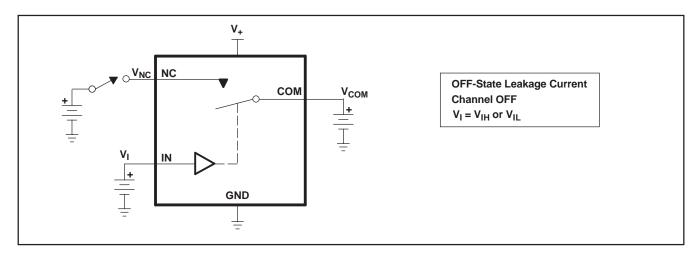


Figure 17. OFF-State Leakage Current ($I_{COM(OFF)}$, $I_{NC(OFF)}$, $I_{COM(PWROFF)}$, $I_{NC(PWR(FF))}$



PARAMETER MEASUREMENT INFORMATION (continued)

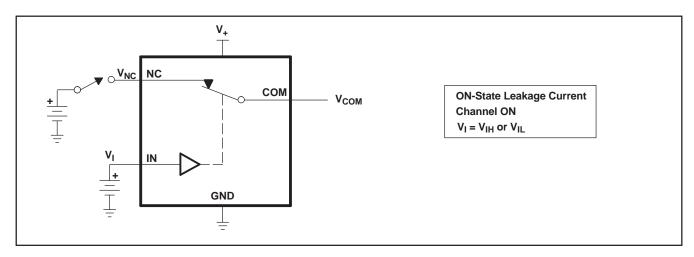


Figure 18. ON-State Leakage Current ($I_{COM(ON)}$, $I_{NC(ON)}$)

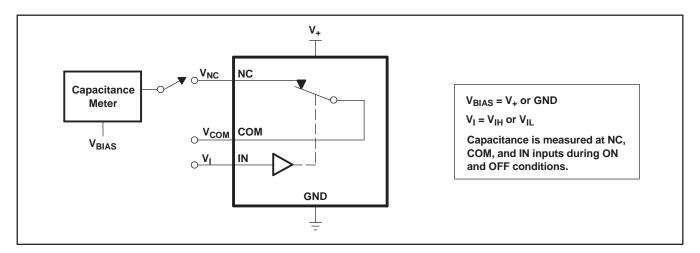


Figure 19. Capacitance (C_I, $C_{COM(OFF)}$, $C_{COM(ON)}$, $C_{NC(OFF)}$, $C_{NC(ON)}$)



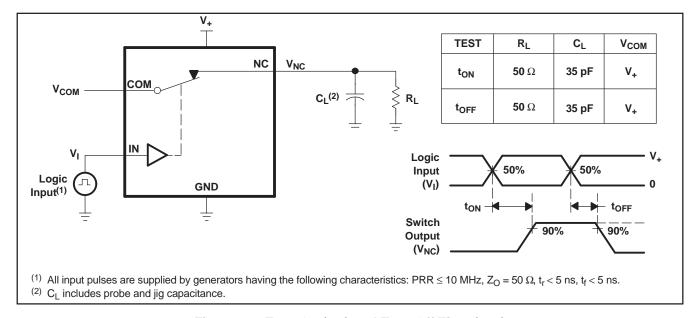


Figure 20. Turn-On (t_{ON}) and Turn-Off Time (t_{OFF})

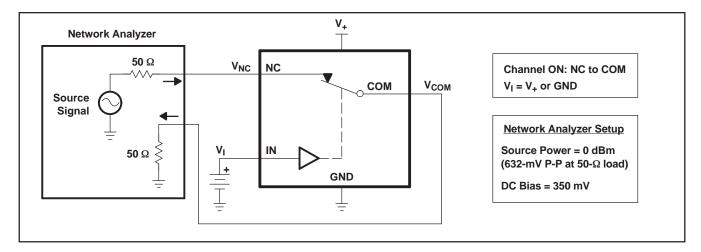


Figure 21. Bandwidth (BW)



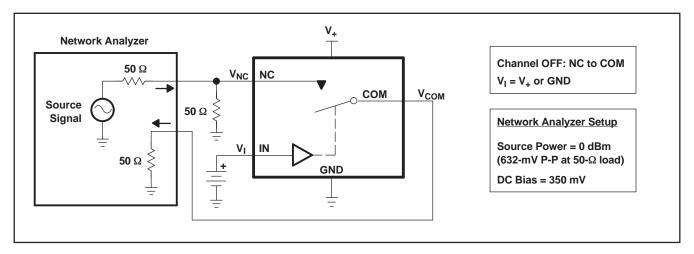


Figure 22. OFF Isolation (O_{ISO})

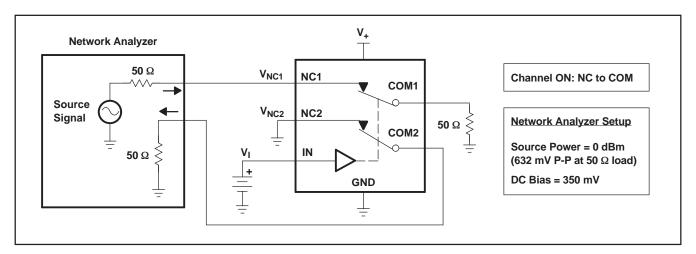


Figure 23. Crosstalk (X_{TALK})



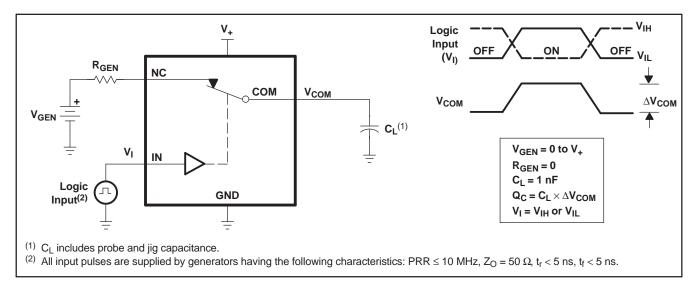


Figure 24. Charge Injection (Q_C)

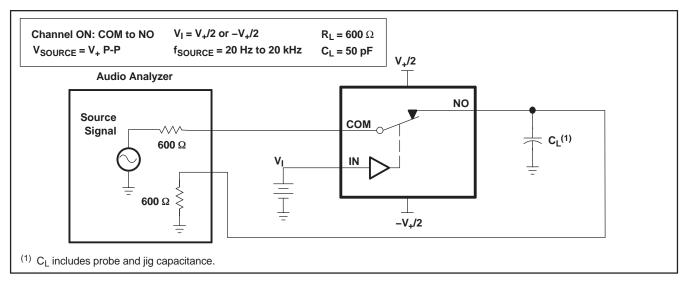


Figure 25. Total Harmonic Distortion (THD)



REVISION HISTORY

Changes from Revision #IMPLIED (May 2005) to Revision A					
•	Updated package options information.	1			



PACKAGE OPTION ADDENDUM

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PACKAGING INFORMATION

www.ti.com

Orderable Device	Status	Package Type	_	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
TS5A23167DCUR	ACTIVE	VSSOP	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 85	(JAPQ ~ JAPR)	Samples
TS5A23167DCURG4	ACTIVE	VSSOP	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	JAPR	Samples
TS5A23167YZPR	ACTIVE	DSBGA	YZP	8	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(J87 ~ J8N)	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

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PACKAGE MATERIALS INFORMATION

www.ti.com 19-Aug-2015

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

All differsions are norminal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS5A23167DCUR	VSSOP	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
TS5A23167DCUR	VSSOP	DCU	8	3000	178.0	9.5	2.25	3.35	1.05	4.0	8.0	Q3
TS5A23167DCURG4	VSSOP	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
TS5A23167YZPR	DSBGA	YZP	8	3000	178.0	9.2	1.02	2.02	0.63	4.0	8.0	Q1

PACKAGE MATERIALS INFORMATION

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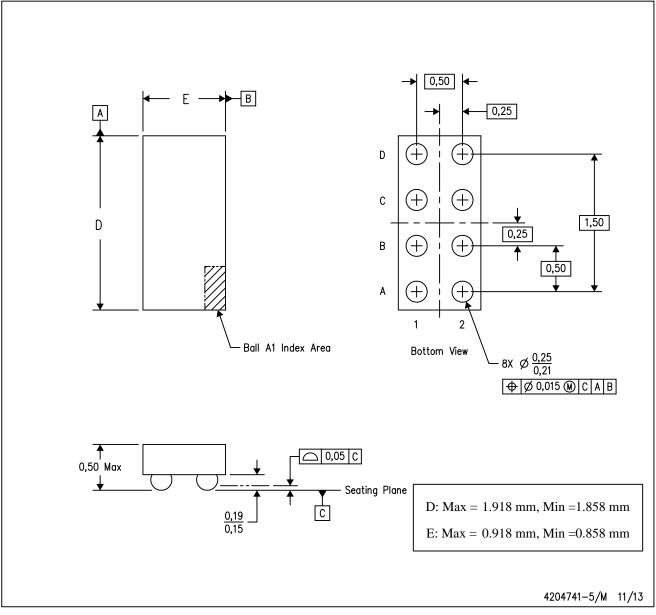


*All dimensions are nominal

7 III GITTIOTIOTOTIO GITO TIOTITITICI							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS5A23167DCUR	VSSOP	DCU	8	3000	202.0	201.0	28.0
TS5A23167DCUR	VSSOP	DCU	8	3000	202.0	201.0	28.0
TS5A23167DCURG4	VSSOP	DCU	8	3000	202.0	201.0	28.0
TS5A23167YZPR	DSBGA	YZP	8	3000	220.0	220.0	35.0

YZP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.

NanoFree is a trademark of Texas Instruments.



DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES:

- : A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-187 variation CA.



DCU (S-PDSO-G8)

PLASTIC SMALL OUTLINE PACKAGE (DIE DOWN)



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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